BGA3023

1.2 GHz 20 dB gain CATV amplifier

Rev. 2 — 25 February 2015 Product data sheet

1. Product profile

1.1 General description

The BGA3023 MMIC is a dual wideband amplifier with internal biasing. It is a Medium Power Amplifier (MPA), specifically designed as an output stage for high linearity CATV optical mini- and midi-nodes, operating over a frequency range of 40 MHz to 1200 MHz.

The MPA is housed in a lead free 8-pin HSO8 package.

1.2 Features and benefits

- Internally biased
- Frequency range of 40 MHz to 1200 MHz
- High linearity with an $IP3_O$ of 46.5 dBm and an $IP2_O$ of 85 dBm
- Operating from 5 V to 8 V supply
- High gain output 1dB compression point of 30 dBm
- 75 Ω input and output impedance
- $I_{CC(tot)}$ can be controlled between 175 mA and 350 mA
- Integrated feedback

1.3 Applications

- CATV infrastructure network medium power output stage in optical nodes (FTTx), distribution amplifiers, trunk amplifiers and line extenders

1.4 Quick reference data

Table 1. Quick reference data

T_{amb} = 25 °C; typical values at V_{CC} = 8 V; Z_S = Z_L = 75 Ω; input and output connected with 1:1 balun, $V_{I(CTRL)}$ = 3.3 V or open (maximum total supply current); 40 MHz ≤ f_1 ≤ 1200 MHz unless otherwise specified.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
V_{CC}	supply voltage	RF input AC coupled	7.6	8.0	8.4	V
$I_{CC(tot)}$	total supply current		-	350	-	mA
T_{amb}	ambient temperature		−40	-	+85	°C
$P_{L(1dB)}$	output power at 1 dB gain compression		-	30	-	dBm
$IP3_O$	output third-order intercept point	[1]	-	46.5	-	dBm
$IP2_O$	output second-order intercept point	[2]	-	85	-	dBm

[1] Fundamental frequency f_1 = 500 MHz, fundamental frequency f_2 = 501 MHz. The intermodulation product (IM3) is measured at $2 \times f_1 - f_2$ = 499 MHz. The output power of the fundamental frequencies is 10 dBm per frequency.

[2] Fundamental frequency f_1 = 240 MHz, fundamental frequency f_2 = 260 MHz. The intermodulation product (IM2) is measured at $f_1 + f_2$ = 500 MHz. The output power of the fundamental frequencies is 10 dBm per frequency.

2. Pinning information

2.1 Pinning

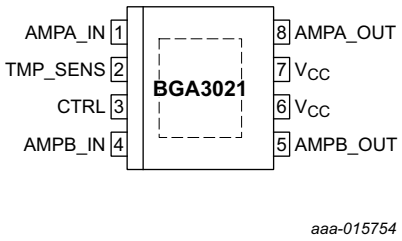


Fig 1. Pin configuration for SOT786-2

2.2 Pin description

Table 2. Pin description

Symbol	Pin	Description
AMPA_IN	1	input amplifier A
TMP_SENS	2	temperature sense
CTRL	3	total supply current control
AMPB_IN	4	input amplifier B
AMPB_OUT	5	output amplifier B [1]
V_{CC}	6	supply [1]
V_{CC}	7	supply [1]
AMPA_OUT	8	output amplifier A [1]
GND	exposed die pad [2]	ground

[1] See Figure 2 for correct connection.

[2] The center metal base of the HSO8 also functions as heatsink for the power amplifier.

3. Ordering information

Table 3. Ordering information

Type number	Package		
	Name	Description	Version
BGA3023	HSO8	plastic thermal enhanced small outline package; 8 leads; body width 3.9 mm; exposed die pad	SOT786-2

4. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{CC}	supply voltage	RF input AC coupled	−0.6	+12	V
$V_{I(CTRL)}$	input voltage on pin CTRL		−0.6	+8	V
$V_{I(TMP\_SENS)}$	input voltage on pin TMP_SENS		−0.6	+8	V
P_i	input power	single tone; on balun [1]	-	20	dBm
T_{stg}	storage temperature		−65	+150	°C
T_j	junction temperature		-	150	°C
T_{amb}	ambient temperature		−40	+85	°C
V_{ESD}	electrostatic discharge voltage	Human Body Model (HBM); According JEDEC standard 22-A114E	2	-	kV
		Charged Device Model (CDM); According JEDEC standard 22-C101B	500	-	V

[1] P_i = 17 dBm on AMPA_IN (pin 1) and AMPB_IN (pin 4).

5. Thermal characteristics

Table 5. Thermal characteristics

Symbol	Parameter	Conditions	Typ	Unit
$R_{th(j-c)}$	thermal resistance from junction to case	[1][2]	15	K/W

[1] Case is ground solder pad.

[2] Thermal resistance measured using infrared measurement technique, device mounted on application board and placed in still air.

6. Characteristics

Table 6. Characteristics at V_{CC} = 8 V; I_{CC} = 350 mA

T_{amb} = 25 °C; typical values at V_{CC} = 8 V; Z_S = Z_L = 75 Ω; input and output connected with 1:1 balun, $V_{I(CTRL)}$ = 3.3 V or open (maximum total supply current); 40 MHz ≤ f_1 ≤ 1200 MHz unless otherwise specified.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
V_{CC}	supply voltage	RF input AC coupled	7.6	8.0	8.4	V
$I_{CC(tot)}$	total supply current		-	350	-	mA
$\|s_{21}\|^2$	insertion power gain	f = 40 MHz	-	20	-	dB
SL_{sl}	slope straight line		-	–2.2	-	dB
FL	flatness of frequency response	[1]	-	0.4	-	dB
$P_{L(1dB)}$	output power at 1 dB gain compression		-	30	-	dBm
$IP3_O$	output third-order intercept point	[2]	-	46.5	-	dBm
$IP2_O$	output second-order intercept point	[3]	-	85	-	dBm
CTB	composite triple beat	V_O = 43 dBmV [4]	-	–64	-	dBc
CSO	composite second-order distortion	V_O = 43 dBmV [4]	-	–75	-	dBc
NF	noise figure	f = 500 MHz	-	5.0	-	dB
RL_{in}	input return loss	f = 40 MHz to 80 MHz	-	–18	-	dB
		f = 80 MHz to 160 MHz	-	–19	-	dB
		f = 160 MHz to 320 MHz	-	–19	-	dB
		f = 320 MHz to 640 MHz	-	–19	-	dB
		f = 640 MHz to 1000 MHz	-	–19	-	dB
		f = 1000 MHz to 1200 MHz	-	–15	-	dB
RL_{out}	output return loss	f = 40 MHz to 80 MHz	-	–17	-	dB
		f = 80 MHz to 160 MHz	-	–19	-	dB
		f = 160 MHz to 320 MHz	-	–17	-	dB
		f = 320 MHz to 640 MHz	-	–17	-	dB
		f = 640 MHz to 1000 MHz	-	–17	-	dB
		f = 1000 MHz to 1200 MHz	-	–14	-	dB

[1] Flatness is defined as peak deviation to straight line.

[2] Fundamental frequency f_1 = 500 MHz, fundamental frequency f_2 = 501 MHz. The intermodulation product (IM3) is measured at $2 \times f_1 - f_2$ = 499 MHz. The output power of the fundamental frequencies is 10 dBm per frequency.

[3] Fundamental frequency f_1 = 240 MHz, fundamental frequency f_2 = 260 MHz. The intermodulation product (IM2) is measured at $f_1 + f_2$ = 500 MHz. The output power of the fundamental frequencies is 10 dBm per frequency.

[4] Measured with 79 NTSC channels.

Table 7. Characteristics at V_{CC} = 8 V; I_{CC} = 175 mA

T_{amb} = 25 °C; typical values at V_{CC} = 8 V; Z_S = Z_L = 75 Ω; input and output connected with 1:1 balun, $V_{I(CTRL)}$ = 0 V (minimum total supply current); 40 MHz ≤ f_1 ≤ 1200 MHz unless otherwise specified.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
V_{CC}	supply voltage	RF input AC coupled	7.6	8.0	8.4	V
$I_{CC(tot)}$	total supply current		-	175	-	mA
$\|s_{21}\|^2$	insertion power gain	f = 40 MHz	-	19.4	-	dB
SL_{sl}	slope straight line		-	–2.7	-	dB
FL	flatness of frequency response	[1]	-	0.5	-	dB
$P_{L(1dB)}$	output power at 1 dB gain compression		-	25	-	dBm
$IP3_O$	output third-order intercept point	[2]	-	38	-	dBm
$IP2_O$	output second-order intercept point	[3]	-	67	-	dBm
CTB	composite triple beat	V_O = 35 dBmV [4]	-	–65	-	dBc
CSO	composite second-order distortion	V_O = 35 dBmV [4]	-	–75	-	dBc
NF	noise figure	f = 500 MHz	-	3.7	-	dB
RL_{in}	input return loss	f = 40 MHz to 80 MHz	-	–20	-	dB
		f = 80 MHz to 160 MHz	-	–20	-	dB
		f = 160 MHz to 320 MHz	-	–18	-	dB
		f = 320 MHz to 640 MHz	-	–18	-	dB
		f = 640 MHz to 1000 MHz	-	–17	-	dB
		f = 1000 MHz to 1200 MHz	-	–13	-	dB
RL_{out}	output return loss	f = 40 MHz to 80 MHz	-	–20	-	dB
		f = 80 MHz to 160 MHz	-	–19	-	dB
		f = 160 MHz to 320 MHz	-	–17	-	dB
		f = 320 MHz to 640 MHz	-	–17	-	dB
		f = 640 MHz to 1000 MHz	-	–17	-	dB
		f = 1000 MHz to 1200 MHz	-	–13	-	dB

[1] Flatness is defined as peak deviation to straight line.

[2] Fundamental frequency f_1 = 500 MHz, fundamental frequency f_2 = 501 MHz. The intermodulation product (IM3) is measured at $2 \times f_1 - f_2$ = 499 MHz. The output power of the fundamental frequencies is 10 dBm per frequency.

[3] Fundamental frequency f_1 = 240 MHz, fundamental frequency f_2 = 260 MHz. The intermodulation product (IM2) is measured at $f_1 + f_2$ = 500 MHz. The output power of the fundamental frequencies is 10 dBm per frequency.

[4] Measured with 79 NTSC channels.

Table 8. Characteristics at V_{CC} = 5 V; I_{CC} = 165 mA

T_{amb} = 25 °C; typical values at V_{CC} = 5 V; Z_S = Z_L = 75 Ω; input and output connected with 1:1 balun, $V_{I(CTRL)}$ = 0 V (minimum total supply current); 40 MHz ≤ f_1 ≤ 1200 MHz unless otherwise specified.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
V_{CC}	supply voltage	RF input AC coupled	4.75	5.00	5.25	V
$I_{CC(tot)}$	total supply current		-	165	-	mA
$\|s_{21}\|^2$	insertion power gain	f = 40 MHz	-	19.5	-	dB
SL_{sl}	slope straight line		-	−2.6	-	dB
FL	flatness of frequency response	[1]	-	0.5	-	dB
$P_{L(1dB)}$	output power at 1 dB gain compression		-	23	-	dBm
$IP3_O$	output third-order intercept point	[2]	-	38	-	dBm
$IP2_O$	output second-order intercept point	[3]	-	68	-	dBm
CTB	composite triple beat	V_O = 35 dBmV [4]	-	−65	-	dBc
CSO	composite second-order distortion	V_O = 35 dBmV [4]	-	−75	-	dBc
NF	noise figure	f = 500 MHz	-	3.7	-	dB
RL_{in}	input return loss	f = 40 MHz to 80 MHz	-	−20	-	dB
		f = 80 MHz to 160 MHz	-	−20	-	dB
		f = 160 MHz to 320 MHz	-	−19	-	dB
		f = 320 MHz to 640 MHz	-	−18	-	dB
		f = 640 MHz to 1000 MHz	-	−18	-	dB
		f = 1000 MHz to 1200 MHz	-	−13	-	dB
RL_{out}	output return loss	f = 40 MHz to 80 MHz	-	−20	-	dB
		f = 80 MHz to 160 MHz	-	−19	-	dB
		f = 160 MHz to 320 MHz	-	−17	-	dB
		f = 320 MHz to 640 MHz	-	−17	-	dB
		f = 640 MHz to 1000 MHz	-	−17	-	dB
		f = 1000 MHz to 1200 MHz	-	−13	-	dB

[1] Flatness is defined as peak deviation to straight line.

[2] Fundamental frequency f_1 = 500 MHz, fundamental frequency f_2 = 501 MHz. The intermodulation product (IM3) is measured at $2 \times f_1 - f_2$ = 499 MHz. The output power of the fundamental frequencies is 10 dBm per frequency.

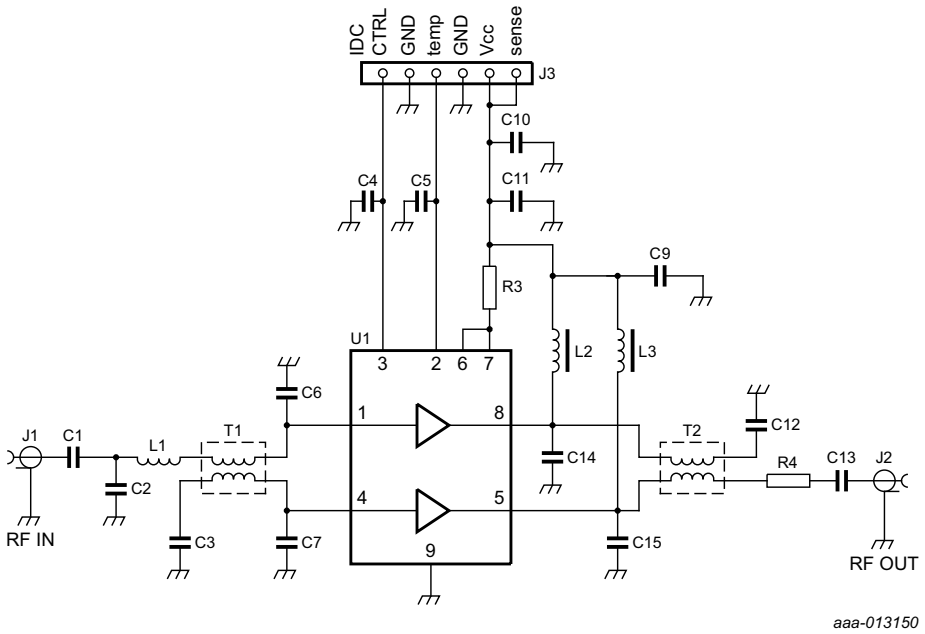
[3] Fundamental frequency f_1 = 240 MHz, fundamental frequency f_2 = 260 MHz. The intermodulation product (IM2) is measured at $f_1 + f_2$ = 500 MHz. The output power of the fundamental frequencies is 10 dBm per frequency.

[4] Measured with 79 NTSC channels.

7. Application information

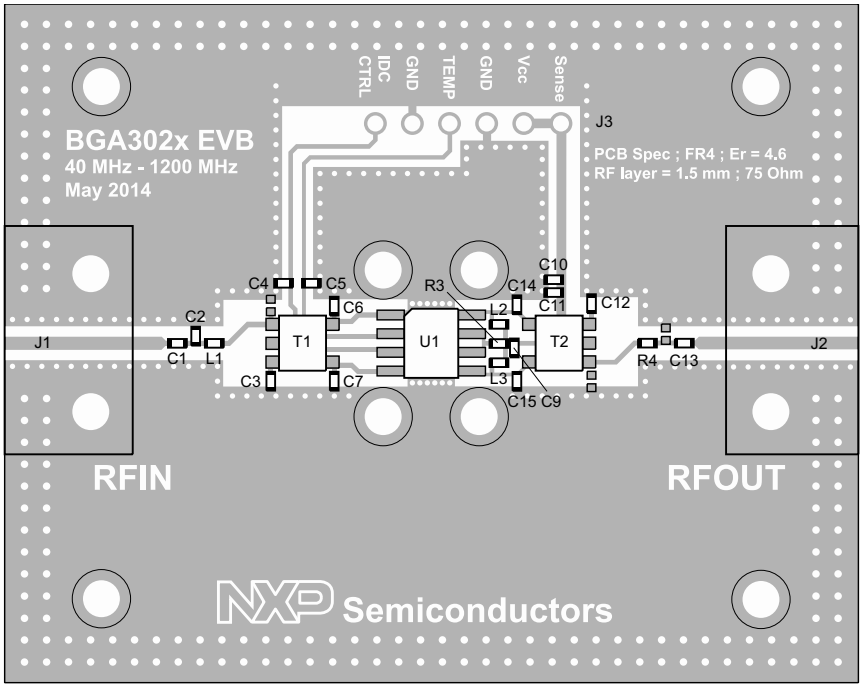
The BGA3023 can be used in other applications. Please contact your local sales representative for more information. Application notes are available on the NXP website.

7.1 Application board



See Table 9 for list of components.

Fig 2. Circuit MPA only evaluation board



See Table 9 for list of components.

Fig 3. Printed-Circuit Board (PCB) layout MPA only evaluation board

Table 9. List of components

See Figure 2 for schematics and Figure 3 for Printed-Circuit Board (PCB).

Component	Description	Value	Remarks
C1, C3, C4, C5, C9, C11, C12, C13	capacitor	10 nF	Murata GRM155R71E103KA01D
C2	capacitor	0.47 pF	Phycomp 2238 869 14477
C10	capacitor	100 nF	Murata GRM155R61A104KA01D
C6, C7, C14, C15	capacitor	1 pF	Murata GRM1555C1H1R0CA01D
J1, J2	F-connector	75 Ω	Bomar 861V509ER6
J3	header 6-pin	-	Molex 22-29-2061
L1	SMD inductor	1.0 nH	Murata LQG15HS1N0S02D
L2, L3	choke	-	Murata BLM15HD182SN1D
R3	chip resistor	15 Ω	Yageo RC0402FR-0715RL
R4	chip resistor	0 Ω	Murata RC0402JR-070RL
T1	balun transformer	-	MACOM MABA-007159-000000
T2	balun transformer	-	MACOM MABA-010245-CT1160
U1	BGA3023	-	NXP

SOT768-2

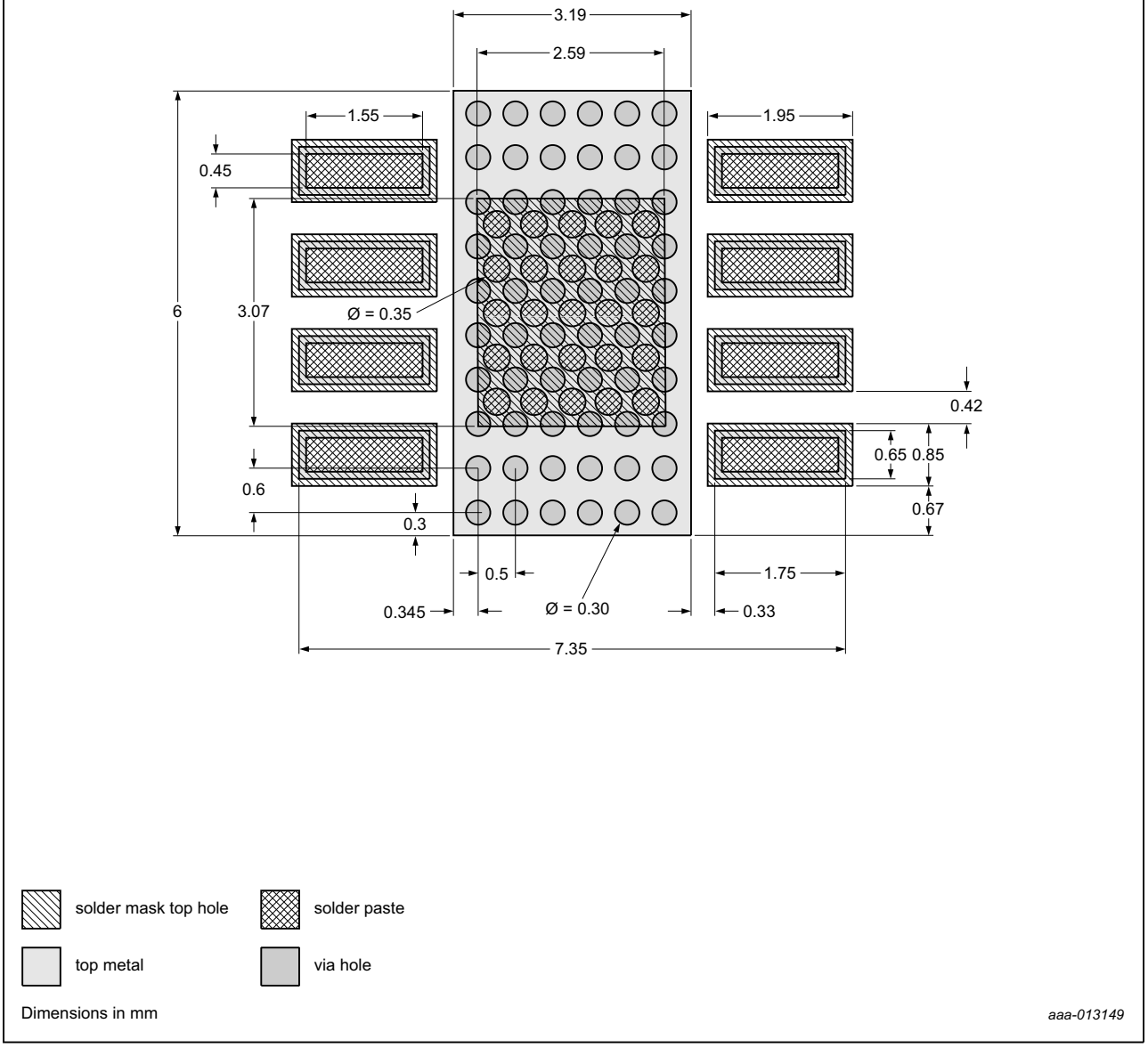
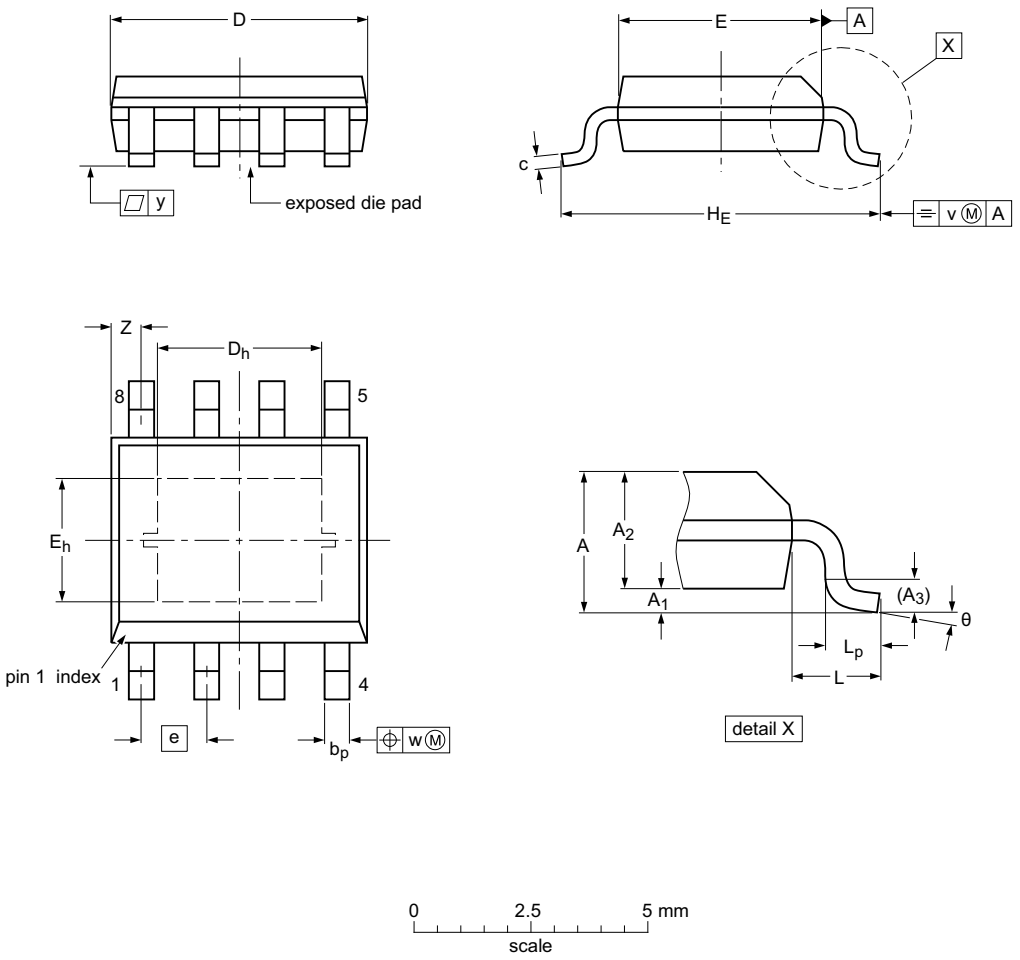


Fig 4. Recommended Printed-Circuit Board (PCB) footprint

8. Package outline

HSO8: plastic thermal enhanced small outline package; 8 leads; body width 3.9 mm; exposed die pad

SOT786-2



Dimensions (mm are the original dimensions)

Unit		A	A_1	A_2	A_3	b_p	c	$D^{(1)}$	D_h	$E^{(2)}$	E_h	e	H_E	L	L_p	v	w	y	$Z^{(1)}$	θ
mm	max		0.1	1.6		0.49	0.25	5.0	3.17	4.0	2.49		6.2		1.0				0.8	8°
	nom	1.7			0.25							1.27		1.05		0.25	0.25	0.1		
	min		0.0	1.4		0.36	0.19	4.8	2.97	3.8	2.29		5.8		0.4				0.3	0°

Note

1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.
2. Plastic or metal protrusions of 0.25 mm maximum per side are not included.

sot786-2_po

Outline version	References				European projection	Issue date
	IEC	JEDEC	JEITA			
SOT786-2						~~13-08-02~~ 14-05-27

Fig 5. Package outline SOT786-2 (HSO8)

9. Abbreviations

Table 10. Abbreviations

Acronym	Description
CATV	Community Antenna TeleVision
FTTx	Fiber To The “x”
MMIC	Monolithic Microwave Integrated Circuit
MPA	Medium Power Amplifier
SMD	Surface Mounted Device

10. Revision history

Table 11. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
BGA3023 v.2	20150225	Product data sheet	-	BGA3023 v.1
BGA3023 v.1	20141128	Preliminary data sheet	-	-

11. Legal information

11.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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[2] The term 'short data sheet' is explained in section "Definitions".

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13. Contents

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